

20V NPN MEDIUM POWER TRANSISTOR IN SOT223

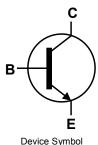
Features

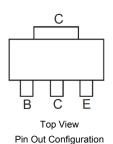
- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DCP69)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen, Antimony and Beryllium Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green Molding" Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin
- Solderable per MIL-STD -202, Method 208
- Weight: 0.112 grams (Approximate)







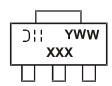
Ordering Information (Note 4)

Part Number	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DCP68-13	Active	Standard	N12	13	12	2,500
DCP68-25-13	Obsolete	Standard	N12-25	13	12	2,500

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen, Antimony and Beryllium-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl), <1000ppm antimony compounds and <1000ppm Beryllium.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



xxx = Product Type Marking Code:
N12 = DCP68
N12-25 = DCP68-25
Code Marking
YWW = Date Code Marking
Y = Last digit of year (ex: 1 = 2021)
WW = Week code (01 - 53)



Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Collector-Base Voltage	V _{CBO}	25	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Continuous Collector Current	Ic	1.0	А

Thermal Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	1	W
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ heta JA}$	125	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to 150	°C

Electrical Characteristics @ T_A = 25°C unless otherwise specified

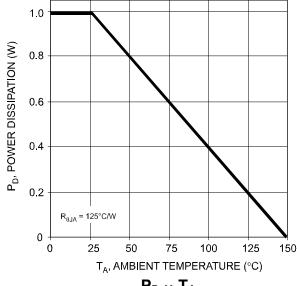
Characteristic			Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)							
Collector-Emitter Breakdown Voltage		BV_CES	25	_	_	V	$I_C = 100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage		BV _{CEO}	20	_	_	V	I _C = 1.0mA, I _B = 0
Collector-Base Breakdown Voltage		BV_{CBO}	25	_	_	V	$I_C = 10\mu A$, $I_E = 0$
Emitter-Base Breakdown Voltage		BV _{EBO}	5.0	_	_	V	$I_E = 10 \mu A$, $I_C = 0$
Collector-Base Cut-Off Current		I _{CBO}	_	_	100	nA	V _{CB} = 25V, I _E = 0
Emitter-Base Cut-Off Current		I _{EBO}	_	_	10	μА	V _{EB} = 5.0V, I _C = 0
ON CHARACTERISTICS (Note 6)							
	DCP68, DCP68-25		50	_	_		$V_{CE} = 10V, I_{C} = 5.0mA$
DC Current Gain		L .	60	_	_		$V_{CE} = 1.0V, I_{C} = 1.0A$
DC Current Gain	DCP68		85		375	-	$V_{CE} = 1.0V, I_{C} = 500mA$
	DCP68-25		160	_	375		$V_{CE} = 1.0V, I_{C} = 500mA$
Collector-Emitter Saturation Voltage		V _{CE(sat)}	_	_	0.5	V	I _C = 1.0A, I _B = 100mA
Base-Emitter Turn-On Voltage		V _{BE (on)}	_	_	1.0	V	$V_{CE} = 1.0V, I_{C} = 1.0A$
SMALL SIGNAL CHARACTERISTICS							
Transition frequency		f _T	_	330	_	MHz	I _C = 100mA, V _{CE} = 5.0V f = 100MHz

Notes:

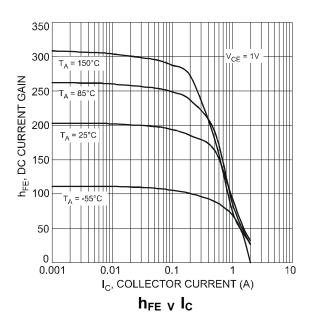
 ^{5.} For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



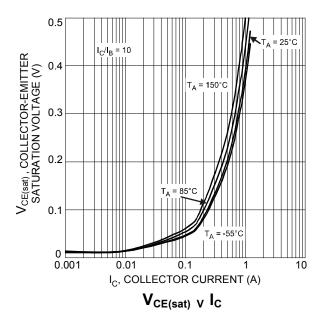
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)





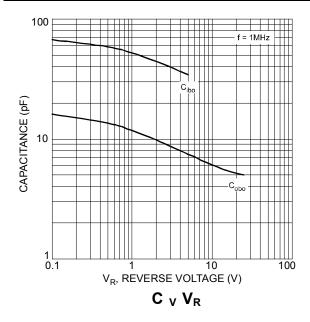


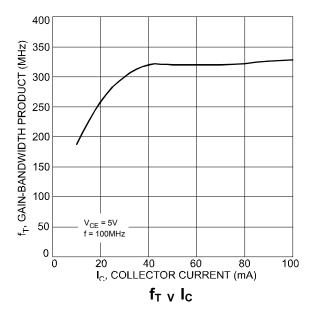
1.6 1.4 I_C, COLLECTOR CURRENT (A) $I_B = 8mA$ 1.2 I_B = 6mA. 1.0 0.8 $I_B = 4mA$ 0.6 0.4 I_B = 2mA 0.2 $I_B = 1mA$ 0.0 10 Ic v VcE

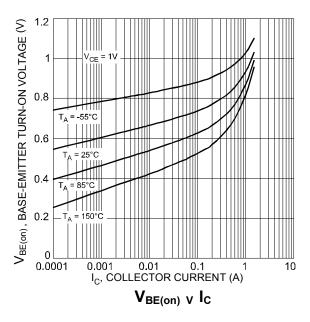


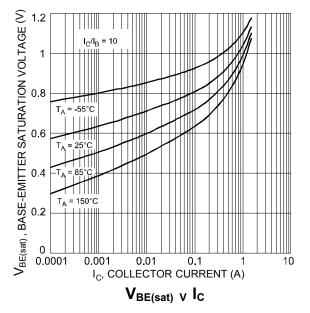


Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)







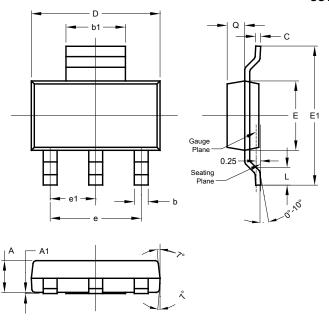




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223

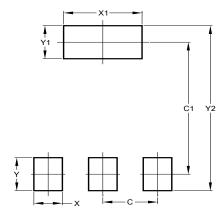


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
V2	8 00



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